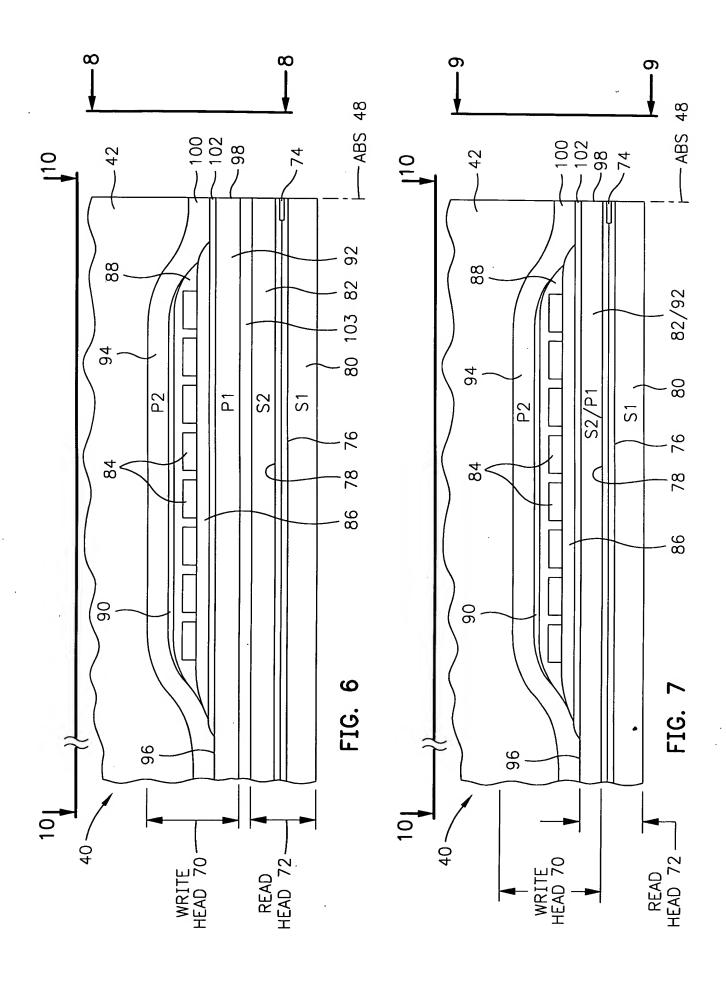
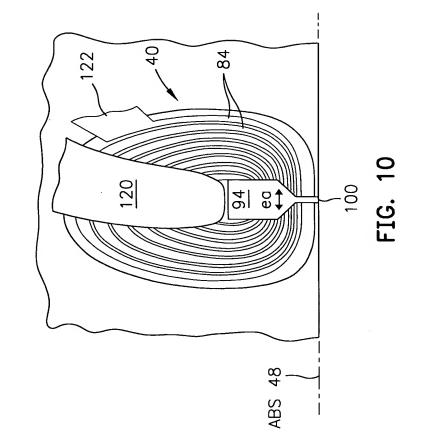
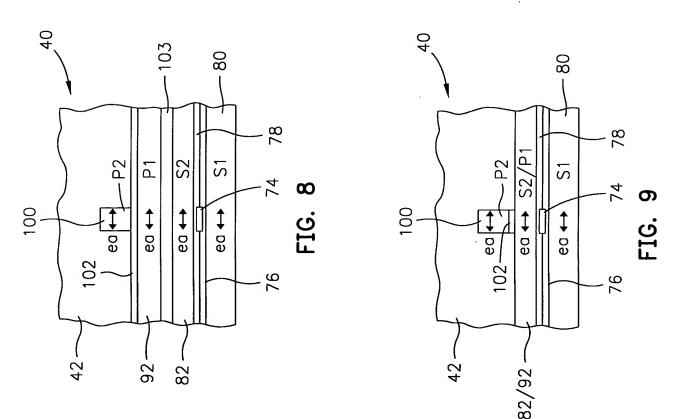


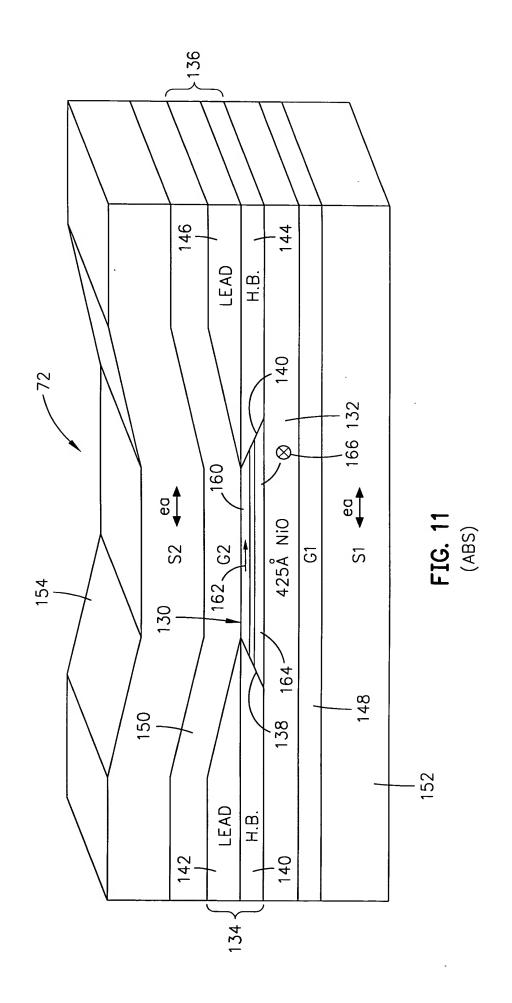
FIG. 5



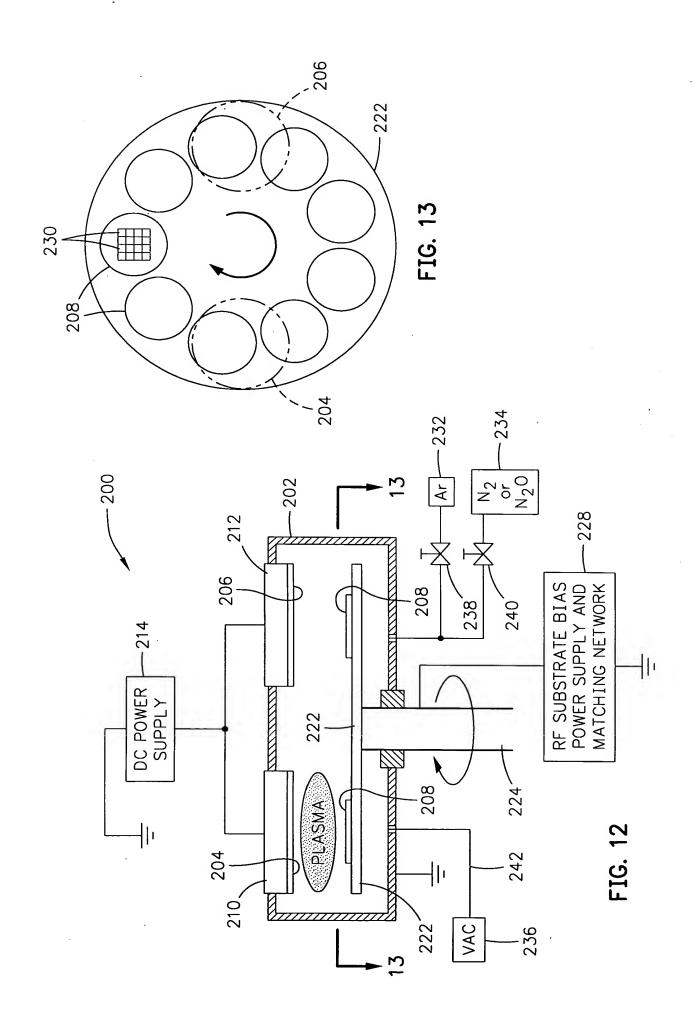


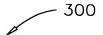












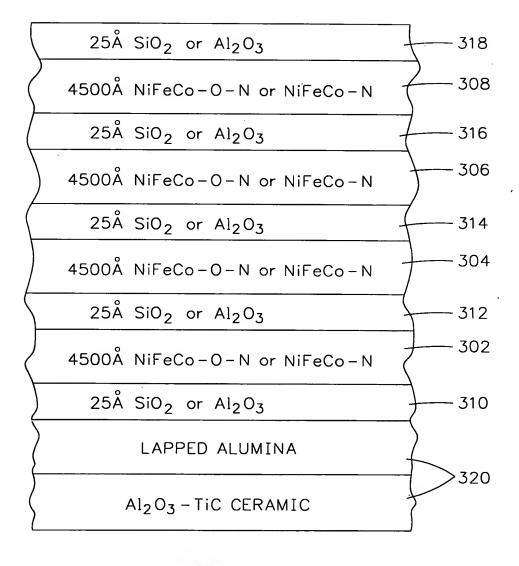
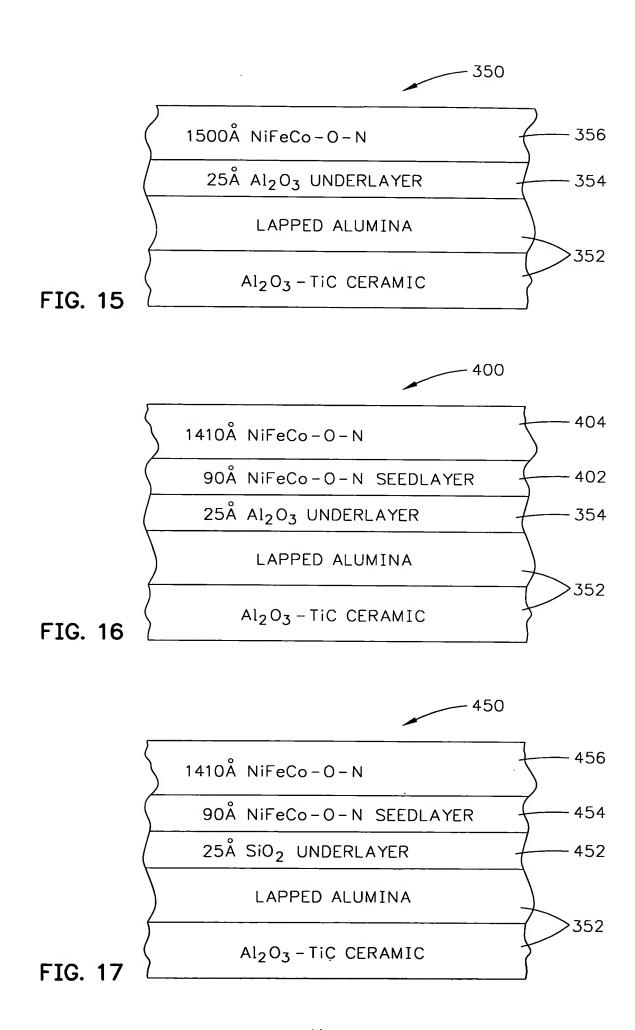
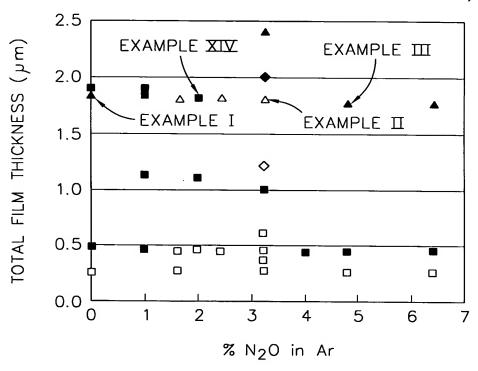


FIG. 14



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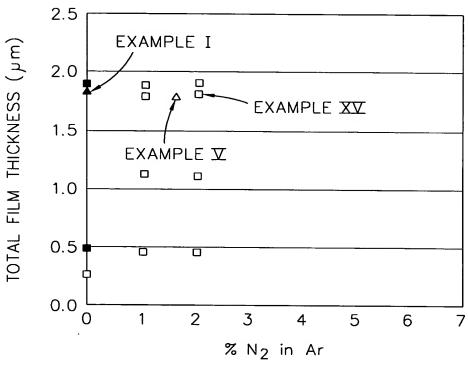
THICKNESS AND N2O CONCENTRATION
DEPENDENCE OF IN-PLANE AND VERTICAL Hk IN
SINGLE LAYER AND LAMINATED NiFeCo-O-N FILMS
(DC MAG 1750 W, 2.0X10<sup>-3</sup> mbar, NO BIAS)



- □ SINGLE LAYER FILMS-IN PLANE Hk
- ♦ 2X LAMINATED FILMS IN PLANE Hk
- △ 4X LAMINATED FILMS-IN PLANE Hk
- SINGLE LAYER FILMS-VERTICAL Hk
- ◆ 2X LAMINATED FILMS-VERTICAL Hk
- ▲ 4X LAMINATED FILMS VERTICAL Hk

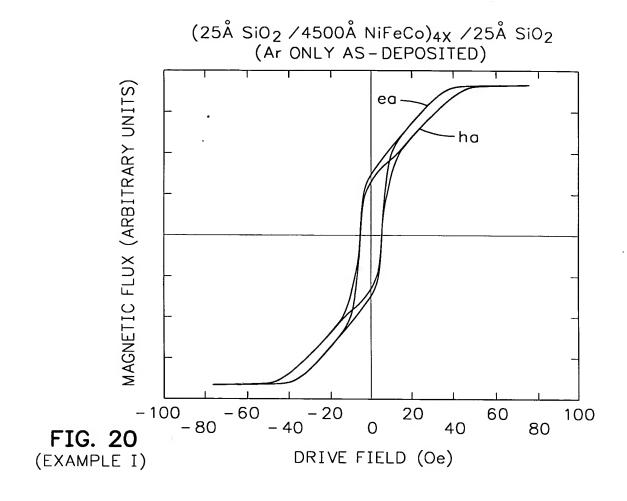
FIG. 18

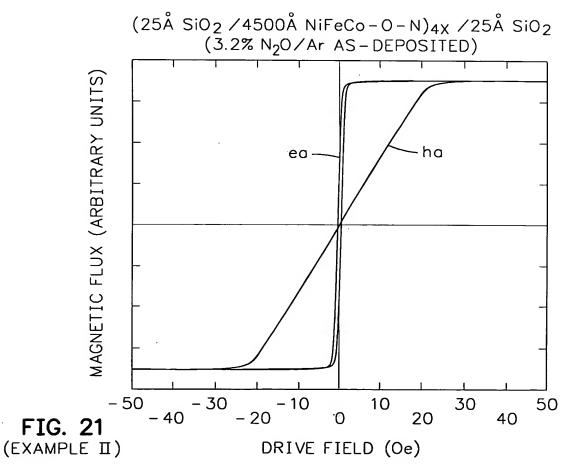
THICKNESS AND N<sub>2</sub> CONCENTRATION
DEPENDENCE OF IN-PLANE AND VERTICAL Hk IN
SINGLE LAYER AND LAMINATED NiFeCo-N FILMS
(DC MAG 1750 W, 2.0X10<sup>-3</sup> mbar, NO BIAS)

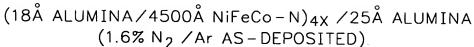


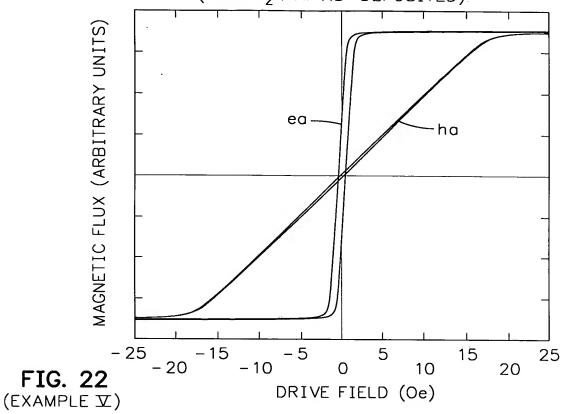
- □ SINGLE LAYER FILMS IN PLANE Hk
- △ 4X LAMINATED FILMS IN PLANE Hk
- SINGLE LAYER FILMS VERTICAL Hk
- ▲ 4X LAMINATED FILMS VERTICAL Hk

FIG. 19

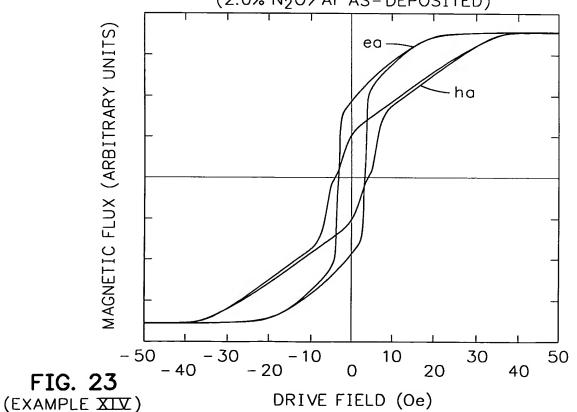








25Å ALUMINA/1.80 µm NiFeCo-O-N/25Å ALUMINA (2.0% N<sub>2</sub>O/Ar AS-DEPOSITED)



25Å ALUMINA/1.80 µm NiFeCo-N/25Å ALUMINA (2.0% N<sub>2</sub> /Ar AS-DEPOSITED)

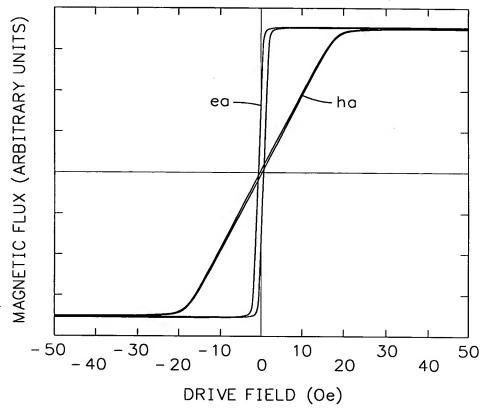
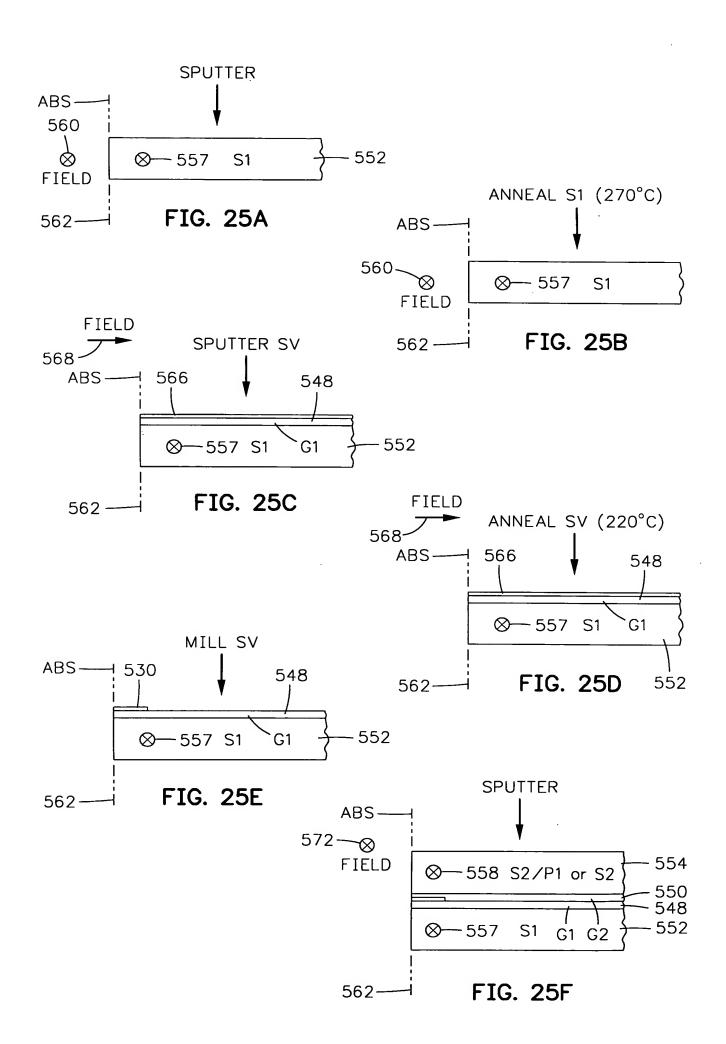
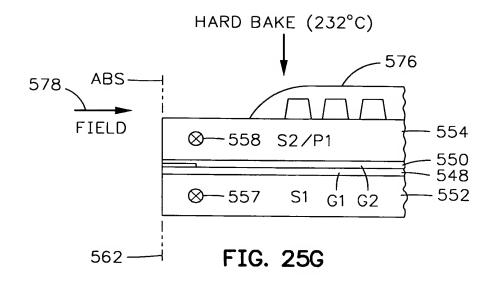
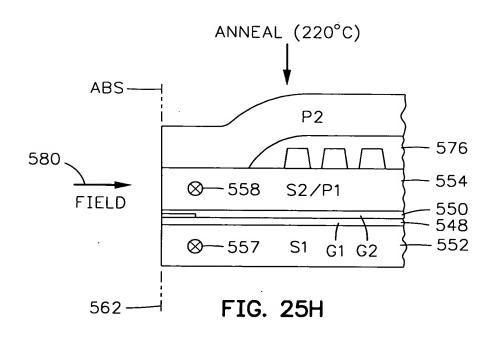
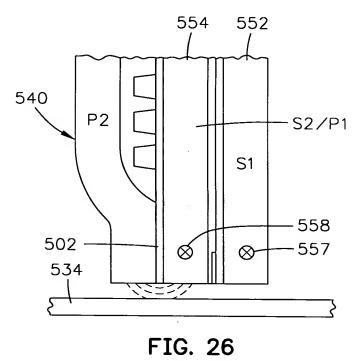


FIG. 24 (EXAMPLE XV)









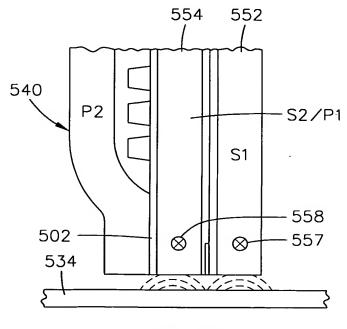
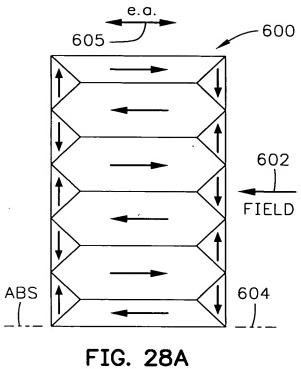


FIG. 27



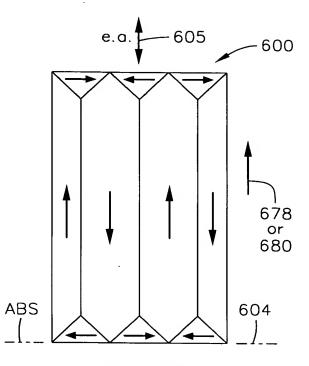
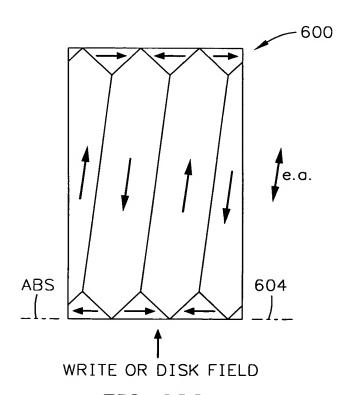


FIG. 28A (PRIOR ART)

FIG. 28B (PRIOR ART)



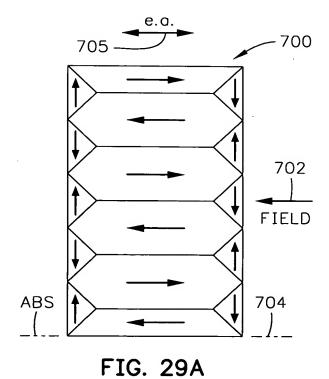


FIG. 28C (PRIOR ART)

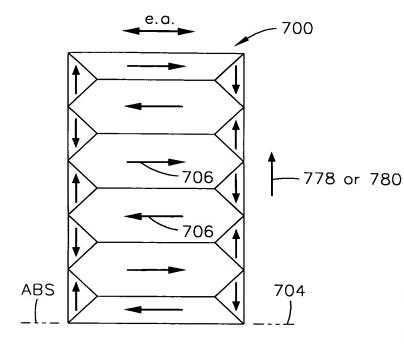


FIG. 29B

NiFeCo[-0]-N AFTER HARDBAKE

ANNEALING OR RESETTING

IN THE PRESENCE OF A FIELD

PERPENDICULAR TO THE ABS

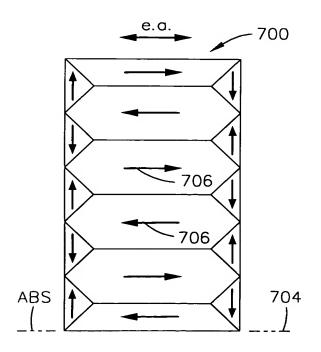


FIG. 29D

